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Intertwined magnetic, structural, and electronic transitions in V_2O_3

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We present a coordinated study of the paramagnetic-to-antiferromagnetic, rhombohedral-to-monoclinic, and metal-to-insulator transitions in thin-film specimens of the classic Mott insulator V_2O_3 using low-energy muon spin relaxation, x-ray diffraction, and nanoscale-resolved near-field infrared spectroscopic techniques. The measurements provide a detailed characterization of the thermal evolution of the magnetic, structural, and electronic phase transitions occurring in a wide temperature range, including quantitative measurements of the high- and low-temperature phase fractions for each transition. The results reveal a stable coexistence of the high- and low-temperature phases over a broad temperature range throughout the transition. Careful comparison of temperature dependence of the different measurements, calibrated by the resistance of the sample, demonstrates that the electronic, magnetic, and structural degrees of freedom remain tightly coupled to each other during the transition process. We also find evidence for antiferromagnetic fluctuations in the vicinity of the phase transition, highlighting the important role of the magnetic degree of freedom in the metal-insulator transition.

INTRODUCTION

Metal-insulator transitions (MITs) in strongly correlated electron materials are among the most intensely studied topics in condensed matter physics. The interest stems from the intellectual richness of strongly interacting electron systems and the close relationship between MITs and exotic phenomena such as high-temperature superconductivity [1–5]. Recent work also shows that MITs hold technological promise for hardware-based artificial neural networks [6–10], intensifying the effort to understand the mechanism of the MIT in various strongly correlated materials.

V_2O_3 is one of the most important materials for studying correlation-induced MITs and the resulting Mott insulating state (used here broadly to refer to an electrically insulating state caused by electron-electron interactions) [11–13]. At ambient pressure, bulk V_2O_3 undergoes an abrupt MIT when cooled below ~ 160 K. A structural phase transition from rhombohedral symmetry in the metallic state to monoclinic symmetry in the insulating state [14] accompanies the MIT, together with antiferromagnetic (AF) ordering of the vanadium moments [15–19]. Extensive theoretical studies have contributed significantly to our understanding of this system [11, 20–29], yet the MIT in V_2O_3 still eludes a comprehensive theoretical description.

A frequent consequence of the coupling among the charge, lattice, and spin degrees of freedom is the spontaneous appearance of inhomogeneous electronic

phases [30]. Recently, this type of phase inhomogeneity was observed directly in V_2O_3 by nanoscale-resolved infrared spectroscopy (nano-IR) [31–33]. These measurements revealed domains of phase-separated metallic and insulating regions throughout the MIT. This nanoscale electronic inhomogeneity is in line with other recent studies on V_2O_3 finding phase separation in the charge sector with Cr doping [34] and the spin sector with pressure [19]. X-ray diffraction studies of V_2O_3 films likewise reveal phase-separated monoclinic and rhombohedral regions in the vicinity of the transition [33, 35].

Related to the observation of intrinsic inhomogeneity across the transition in V_2O_3 is the crucial issue of whether the electronic, structural, and AF transitions occur simultaneously or can be decoupled from each other. Such decoupling would have significant implications for our understanding of what drives the Mott transition and for potential technological applications. A recent study of V_2O_3 films combining X-ray diffraction, IR spectroscopy, and transport showed that the electronic and structural transitions are simultaneous [35]. However, no equivalent work investigating the AF transition in V_2O_3 films has been reported.

Here, we present low-energy muon spin relaxation/rotation (μ SR) experiments on films of V_2O_3 to determine quantitatively the magnetically ordered phase fraction across the transition, thereby filling the gap left by the earlier works. We also performed temperature-dependent x-ray diffraction (XRD) and nano-IR measurements on the same specimens, offering a uniquely

complete picture of the MIT in V_2O_3 . Using the sample resistance to calibrate the temperature between the μ SR and XRD instruments, we quantitatively compare the magnetic and structural phase fractions across the transition. The midpoints of the magnetic and structural transitions are indistinguishable within the experimental sensitivity of ~ 1 K, but magnetic correlations develop in a partial volume fraction beginning ~ 10 K above the onset of the structural transition. This suggests that antiferromagnetism plays a dominant role in the MIT.

EXPERIMENTAL DETAILS

Two sets of V_2O_3 films of thickness 300 nm and 70 nm, respectively, were grown on a sapphire substrate cut so that the (012) plane is in the out-of-plane direction of the film. We followed the procedure in Ref. 36, except that the films in the present work were pristine, not annealed. These samples were characterized with low-energy μ SR at the Paul Scherrer Institut. To prepare each sample for the μ SR measurements, six identical films of dimensions $12\text{ mm} \times 7\text{ mm}$ were tiled together and adhered to a nickel plate, which was inserted in the μ SR spectrometer on the LEM (Low Energy Muon) beamline at the Paul Scherrer Institute. A pseudo-continuous beam of 100% spin-polarized muons with initial energies of 4 MeV was slowed by a moderator to energies of about 15 eV, then electrostatically accelerated to a desired energy on the order of 10 keV, allowing implantation of the muons selectively at a variable mean depth ranging from 10 nm to several tens of nm.

In a μ SR experiment, implanted muons will stop at a site in the crystal corresponding to an electrostatic potential minimum. The spin of each muon precesses around the magnetic field at this site until the muon decays with a mean lifetime of $2.2\text{ }\mu\text{s}$ into two neutrinos and a positron, the latter being emitted preferentially along the direction of the muon spin at the moment of decay. The normalized difference in positron counts between pairs of opposing positron detectors near the sample is known as the μ SR asymmetry and is proportional to the projection of the muon ensemble spin polarization along the axis defined by the detector pair. Tracking the asymmetry as a function of time after muon implantation therefore provides detailed information about the local magnetic field distribution in the sample.

Integrating the muon beam intensity profile over the sample area indicated that for both samples, 85% of the muons landed in the sample area and the remaining 15% in the nickel plate, which contributes a featureless exponential decay that disappears well before $0.1\text{ }\mu\text{s}$ in the asymmetry spectra. Of muons landing in the sample area, $10 \pm 3.5\%$ landed in exposed areas of the sapphire substrate, contributing a small and extremely rapid decay that manifests only as absent asymmetry within the

time-binning used for the data analysis. Therefore, the dominant features observed are intrinsic to the V_2O_3 films.

The same samples used for the μ SR experiments were also characterized with XRD using a Rigaku Smartlab instrument equipped with a variable temperature stage as described elsewhere [35]. The temperatures measured during the μ SR and XRD experiments on the 300-nm sample were precisely calibrated to each other in the following way. *In situ* measurements of the resistance R were performed during the μ SR and XRD experiments, and the measured values were compared to precise R versus T measurements conducted on a separate probe station. The same contact points on the film were used in each case. To account for different contact resistances, the R values measured during the μ SR and XRD experiments were corrected by adding a constant value such that the minimum resistance (i.e., the resistance in the metallic state at a temperature just above the onset of the MIT) agreed with the minimum resistance measured on the probe station. This offset was $9.8\text{ }\Omega$ for the μ SR measurements and $2.4\text{ }\Omega$ for XRD. For a given (corrected) value of R measured during the μ SR or XRD experiments, the calibrated temperature was taken to be the corresponding temperature measured on the probe station. This procedure was not performed during any of the experiments on the 70-nm sample, so we regard the temperatures reported for that sample to be unsuitable for quantitative comparison among the different experimental techniques. In addition to the μ SR and XRD characterization, the 70-nm sample was further studied by nano-IR with a spatial resolution of $\sim 25\text{ nm}$ using methods described previously [33].

RESULTS AND DISCUSSION

μ SR Characterization

We first present μ SR measurements of the 300-nm sample in zero external field (ZF) to probe the intrinsic AF order in the sample. In Fig. 1(a), we display representative ZF spectra measured with 15-keV muons, corresponding to a mean stopping depth of $70 \pm 20\text{ nm}$. The overlaid black curves show fits using a model consisting of an exponential component for the background from the nickel mounting plate (visible as the slight decay at early time for the 200 K spectrum), an exponentially damped cosine function for the oscillations of the muon spin component transverse to the local magnetic field, and an exponential component for the spin component longitudinal to the local field. Above the AF ordering temperature T_N , the asymmetry contribution from V_2O_3 relaxes slowly with time (too slowly to be observed in Fig. 1(a)), as expected for a paramagnet. Coherent oscillations develop below T_N , reflecting the establishment of long-range magnetic order. These oscilla-

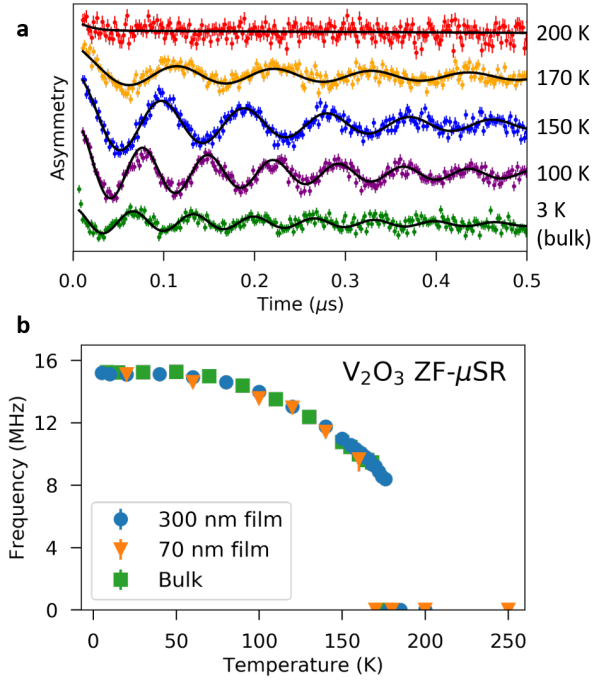


FIG. 1. (Color online) (a) ZF μ SR time spectra from the 300-nm sample measured in a warming sequence spanning the antiferromagnetic ordering temperature, offset vertically for clarity. A spectrum collected from bulk V_2O_3 is also shown. (b) Oscillation frequencies for the 300-nm, 70-nm, and bulk samples of V_2O_3 extracted from least-squares refinements performed against the ZF spectra. Error bars represent the estimated standard deviation (ESD) of the frequency determined by the refinements. Note that the 70-nm film data were collected on cooling and the others on warming.

tions are well described by a single oscillating frequency, which we extracted from least-squares refinements and display as blue circles in Fig. 1(b). This frequency is proportional to the magnitude of the staggered AF moment. Upon warming, the frequency decreases steadily until oscillations abruptly disappear at 176 K. Equivalent analysis on the 70-nm sample with 8-keV muons (stopping depth of 40 ± 20 nm) yields very similar results (orange triangles in Fig. 1(b)). For comparison, we also display the ZF spectra of bulk V_2O_3 measured at 3 K at the TRIUMF μ SR facility at the bottom of Fig. 1(a) and the corresponding oscillation frequencies for the bulk sample as green squares in panel (b). The bulk and film samples display nearly identical behavior, indicating they share the same magnetic ground state. Further measurements using varying muon energies indicate there is no significant depth-dependence to the magnetism [see the Supplemental Material [37]]. The substantial reduction of the oscillation frequency when approaching T_N from below agrees with previous work [16].

To quantify the temperature dependence of the magnetically ordered phase fraction in the 300-nm sample, we performed measurements in a weak field (~ 50 G) di-

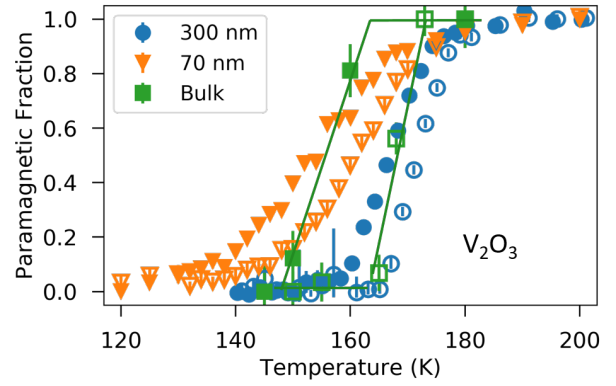


FIG. 2. (Color online) Temperature evolution of the paramagnetic phase fraction in V_2O_3 for the 300-nm, 70-nm, and bulk samples. Filled symbols represent data taken in a cooling sequence, open symbols in a warming sequence.

rected transverse to the initial muon spin (wTF configuration) using 15 keV muons. The spins of muons landing in paramagnetic regions of the sample exhibit slow precession around the weak external field, while the spins of muons landing in magnetically ordered regions precess rapidly around the vector sum of the small external field and the much larger local intrinsic field (~ 1.1 kG at 5 K). Within the longer time window used to view and analyze wTF data, the signal from muons landing in ordered regions appears as missing initial asymmetry or a non-oscillating component. Representative wTF spectra are shown in the Supplemental Material. Comparing the temperature-dependent amplitude $a(T)$ of the slow oscillations arising from muons in paramagnetic regions to the measured initial total asymmetry well above the transition a_{max} , the paramagnetic phase fraction can be determined as $[a(T) - a_{\text{min}}]/(a_{\text{max}} - a_{\text{min}})$. Here, a_{min} is the minimum amplitude in the fully AF state and is very close to zero (~ 0.01). This asymmetry is within the typical background contribution at the low-energy μ SR spectrometer used in this study. However, other contributions from minute non-magnetic regions in the sample cannot be ruled out, such as very thin amorphous phases known to form on the surface.

The paramagnetic phase fraction is plotted for the 300-nm sample (blue circles) and 70-nm sample (orange triangles) in Fig. 2. Open (filled) symbols represent data collected on warming (cooling). Although the onset temperature is similar for the two samples (roughly 175 K), the transition progresses more rapidly with temperature in the 300-nm sample, completing at ~ 155 K compared to ~ 120 K for the 70-nm sample. The paramagnetic fraction of bulk V_2O_3 determined from earlier μ SR measurements [16] is shown for comparison (green squares). The bulk transition is sharper than that in either of the film samples, completing within a temperature range of ~ 15 K, and exhibits a somewhat wider thermal hysteresis, consistent with other neutron and muon stud-

ies [15, 38].

These results reveal a relatively slow development of AF order across the transition in the film samples. In the broad temperature interval over which the transition occurs, the magnetic state of the system is inhomogeneous, separated into paramagnetic regions and AF regions. This is similar to the separation into rhombohedral/triclinic regions and metallic/insulating regions reported in previous studies of V_2O_3 films [33, 35].

Quantitative Comparison of Magnetic and Structural Phase Fractions

We now present a quantitative, temperature-calibrated comparison of the thermal evolution of the paramagnetic and rhombohedral phase fractions of the 300-nm sample to determine whether the two transitions occur simultaneously or separately. XRD measurements were performed between 180 K and 140 K in both cooling and warming sequences. The structural transition causes the (012) rhombohedral Bragg peak to transform into the (011) monoclinic peak, which are separated enough in reciprocal space to be easily distinguished [35]. In the XRD patterns collected at intermediate temperatures across the transition, both peaks are clearly observable, indicating coexistence of the two phases. To quantify the rhombohedral phase fraction, Lorentzian and Gaussian curves were fit to the (012) rhombohedral and (011) monoclinic Bragg peaks and their relative weights compared [35]. The uncertainty of this calculation is approximately 10% [39]. In Fig. 3(a), we display the rhombohedral and paramagnetic phase fractions with red triangles and blue circles, respectively.

The paramagnetic and rhombohedral phase fractions show a very similar temperature evolution on both warming and cooling. Within an uncertainty of ~ 1 K, the temperature $T_{1/2}$ at which the high temperature phase occupies half the sample volume (i.e., the center of the transition) is identical for both the magnetic and structural transitions (167 K on cooling, 171 K on warming). The completion temperatures of the two transitions are likewise very similar. One significant difference between the two transitions is that the temperature at which the paramagnetic fraction begins to drop below unity (~ 185 K) is higher than that of the rhombohedral fraction (~ 175 K). This observation will be discussed subsequently.

Taking a more quantitative approach, we display the numerical derivative df/dT of the high-temperature phase fraction f with respect to temperature T in Fig. 3(b). For simplicity, only the data collected on cooling are considered. We fit a normalized Gaussian model of the form $df/dT = \frac{1}{\sigma\sqrt{2\pi}} \exp\left[-\frac{(T-T_0)^2}{2\sigma^2}\right]$ to the data, with the best fits displayed as solid curves in Fig. 3(b). Table I compares the refined parameters. The fitted values of T_0 (the temperature at which the phase fraction

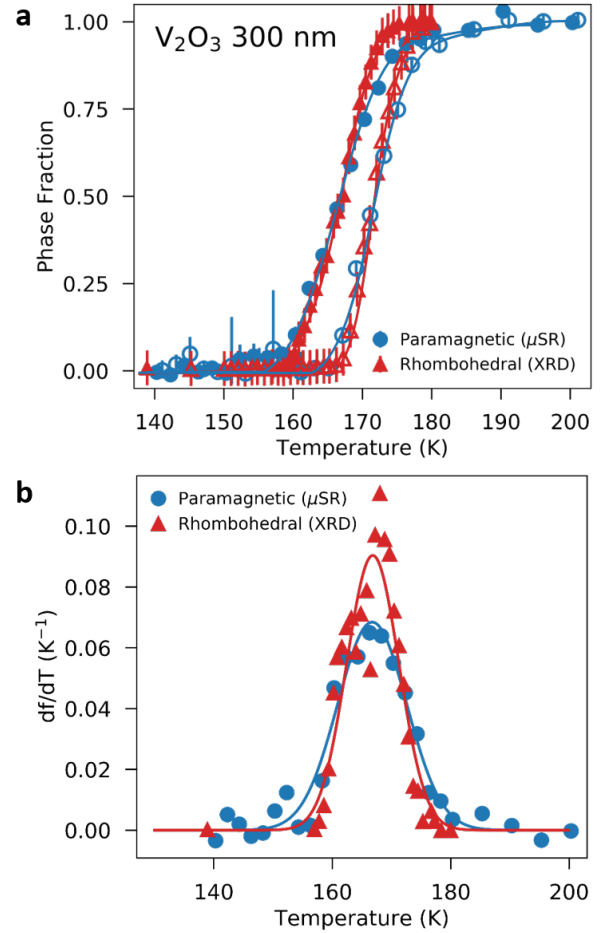


FIG. 3. (Color online) (a) Paramagnetic and rhombohedral phase fractions for the 300-nm film. Filled (open) symbols represent data collected on cooling (warming). (b) Temperature derivative of the phase fractions plotted in (a), with Gaussian fits to the data displayed as solid curves.

changes most rapidly) are identical for the two transitions within the fit uncertainty of ~ 0.3 K, and also agree closely with the measured $T_{1/2} = 167$ K. This confirms that the two transitions remain tightly coupled in temperature. For the magnetic transition, the width σ is somewhat larger than for the structural transition, which is related to the higher onset temperature in the μ SR data mentioned previously.

TABLE I. Refined Gaussian parameters of the temperature derivative of the low-temperature magnetic and structural phase fractions.

	T_0 (K)	σ (K)
Magnetic	166.7 ± 0.2	5.8 ± 0.2
Structural	166.8 ± 0.3	4.4 ± 0.2

This quantitative comparison of the magnetic and structural transitions in V_2O_3 films fills an important gap in the existing body of experimental work and pro-

vides strong evidence that the magnetic and structural transitions remain tightly coupled. Together with the recent report of robust coupling of the structural and electronic transitions in identically prepared films [35], these experiments indicate that the transition in V_2O_3 occurs simultaneously in the magnetic, structural, and electronic sectors. The magnetic and structural phase fractions of the 70-nm sample were also measured and found to be similar to the 300-nm sample, including an apparently higher-temperature onset of the magnetic transition than the structural transition (see Fig. 4(b)), but the lack of precise temperature calibration between the measurements prevents a more quantitative comparison.

The observation that the paramagnetic fraction begins to decrease at a higher temperature than does the rhombohedral phase fraction merits further discussion. This suggests that quasi-static magnetic correlations develop in a partial volume fraction above the structural phase transition, causing the paramagnetic volume to drop below unity. We expect these to be short-range correlations, since coherent ZF oscillations indicative of genuine long-range magnetic order do not appear until lower temperatures. Given earlier neutron scattering data demonstrating the existence of short-range critical AF fluctuations above T_N [40, 41], this gradual reduction of the paramagnetic fraction at high temperature is likely due to partial pinning of these AF fluctuations. Such fluctuations would be expected for a continuous phase transition, despite the fact that the AF transition in V_2O_3 is first order. This suggests that the critical point of a continuous transition is located nearby in parameter space. Similarly, we note that the ZF precession frequency displayed in Fig. 1(b) shows a pronounced reduction when approaching the transition temperature from below (which would be expected for a continuous magnetic phase transition), but the smooth evolution is ultimately interrupted in first-order-like fashion at a temperature close to the structural phase transition. This is further evidence that the magnetic transition is nearly continuous but is rendered first-order by the structural phase transition. Such a situation is also found in the perovskite rare-earth nickelate Mott systems [19]. We note that these results support recent magnetotransport data and theoretical calculations [42], which suggest that magnetism plays the dominant role in V_2O_3 through a Mott-Slater mechanism for the MIT.

nanoIR Characterization

Having examined the magnetic and structural transitions, we complete our study by probing the MIT through nano-IR measurements of the 70-nm sample. Spatially resolved maps of the local IR response were generated at several temperatures spanning the transition. In Fig. 4(a), we display a representative image

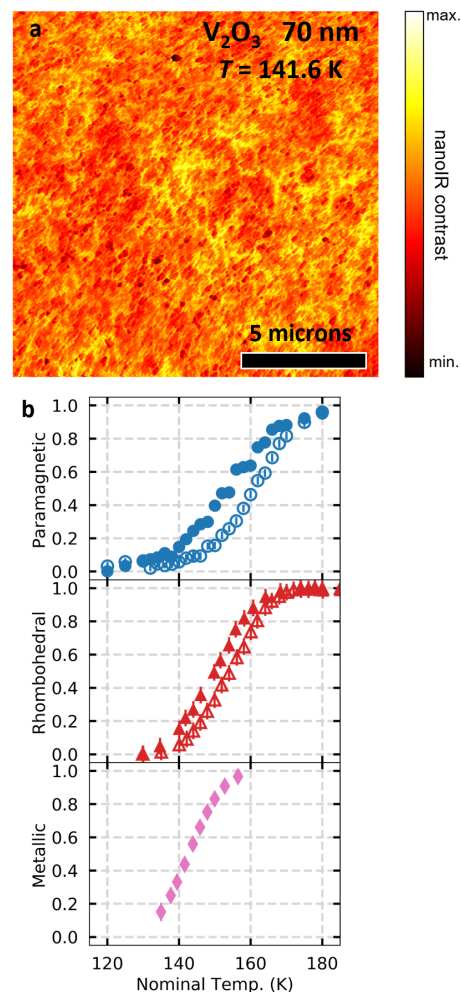


FIG. 4. (Color online) (a) Nano-IR measurements of the 70-nm sample of V_2O_3 at a nominal temperature of 141.6 K showing spatial phase separation between metallic (light-colored) and insulating (dark-colored) domains. (b) Paramagnetic, rhombohedral, and metallic phase fractions for the 70 nm film as a function of nominal temperature (note that the thermometry was not calibrated between experimental techniques). Filled (open) symbols represent data collected on cooling (warming).

taken at a nominal temperature of 141.6 K. Micron-scale metallic and insulating domains (light and dark regions, respectively) coexist in a spatially segregated manner, confirming that widespread electronic inhomogeneity across the transition accompanies the magnetic and structural inhomogeneity described previously.

These maps of the local IR response can be analyzed to estimate the metallic and insulating fractions for comparison with the magnetic and structural phase fractions. Details of this procedure are provided in the Supplemental Material. In Fig. 4(b), we display the metallic phase fraction together with the previously described paramagnetic and rhombohedral phase fractions determined for the same 70-nm sample. The temperature evolution of

all three transitions is qualitatively similar, exhibiting a gradual development of the low-temperature phase over a ~ 30 K interval centered roughly around 150 K. A quantitative comparison is not possible due to the absence of *in-situ* resistance measurements to enable accurate temperature calibration across the three experimental setups. The apparent differences in the midpoint transition temperature of the magnetic, structural, and electronic transitions evident in Fig. 4(b) should therefore be treated cautiously. Nevertheless, it is clear that real-space phase separation between the low- and high-temperature states occurs over a similar temperature interval in all three sectors. The application of these three complementary techniques to the same 70-nm specimen represents a uniquely complete characterization of the magnetic, structural, and electronic phase transitions in V_2O_3 .

SUMMARY

We have reported complementary μ SR, XRD, and nano-IR measurements of two samples of V_2O_3 in thin-film form. The experimental results reveal real-space phase segregation between the low- and high-temperature phases throughout the magnetic, structural, and electronic transitions. Furthermore, we presented a quantitative comparison of the antiferromagnetic and monoclinic phase fractions with precisely calibrated thermometry, enabling an unambiguous comparison of the magnetic and structural phase evolution. We found that the midpoints of the two transitions occur simultaneously within our experimental sensitivity of ~ 1 K, consistent with the simultaneous structural and electronic transitions reported previously [35]. Together, these results demonstrate that the spin, lattice, and charge sectors remain tightly coupled across the Mott transition in V_2O_3 . However, we also observe evidence for AF fluctuations at temperatures both above and below the structural phase transition. At low temperature, this manifests as a smooth reduction of the ZF- μ SR oscillation frequency; at high temperature, as a reduction of the paramagnetic phase fraction with no observable ZF oscillations. This suggests that both the low- and high-temperature phases of V_2O_3 are close to continuous AF phase transitions which are preempted by a structural transition, rendering the MIT first order. These findings suggest that magnetism plays an important role in the MIT, in agreement with recent experimental and theoretical work [42].

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